

# Measurement of gas gain fluctuations

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*TPC Jamboree, Orsay, 12/05/2009*

# Overview

- Introduction
  - Motivations, questions and tools
- Measurements
  - Energy resolution & electron collection efficiency  
*Micromegas-like mesh readout*
  - Single electron detection efficiency and gas gain  
*TimePix readout*
- Conclusion

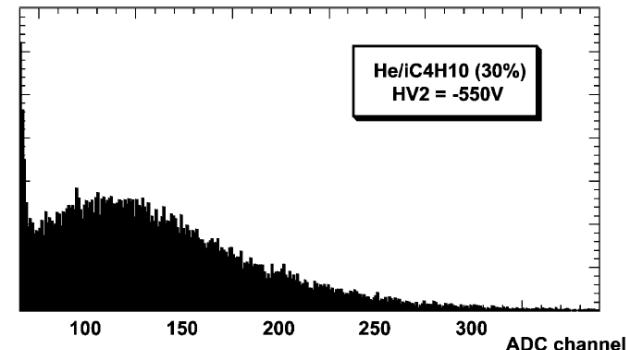
# Gas gain fluctuations

- Final avalanche size obeys a probability distribution  
Signal fluctuations impact on detector performance
  - Spatial resolution in a TPC
  - Energy resolution in amplification-based gas detectors
  - Minimum gain and ion backflow
  - Detection of single electrons with a pixel chip
- What is the shape of the distribution?  
How does it vary with gas, field, geometry...?
- The Polya distribution parametrized by gas gain  $G$  and parameter  $m$ 
  - Works well with Micromegas/PPC/MCP/single GEM
  - With GEM stacks, distribution is more exponential

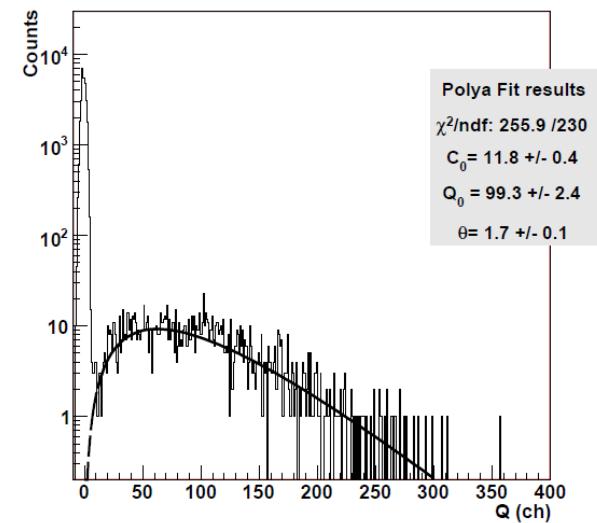
$$p_m(g) = \frac{m^m}{\Gamma(m)} \frac{1}{G} \left( \frac{g}{G} \right)^{m-1} \exp(-mg/G)$$

$$\sigma^2 = 1/m = b, \text{relative gain variance}$$

*Micromegas, NIMA 461 (2001) 84*



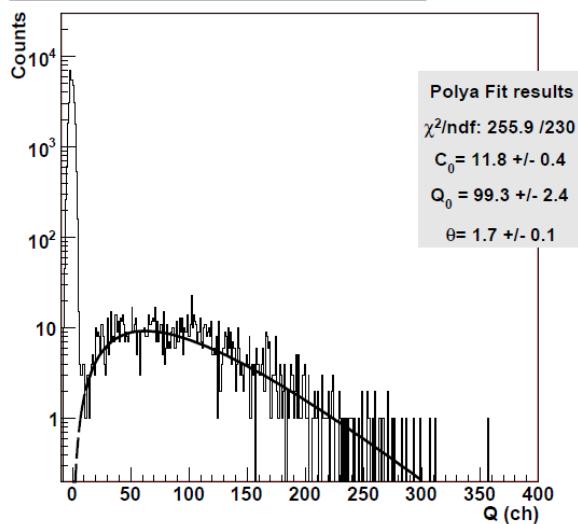
(e) SER Ne 95% iC<sub>4</sub>H<sub>10</sub> 5% - V<sub>Mesh</sub> = 510V



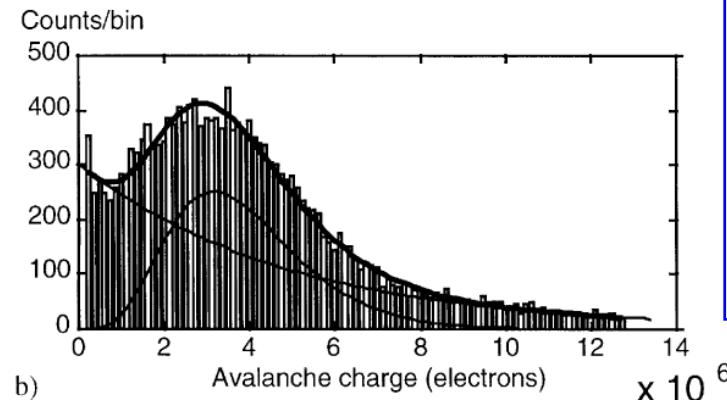
*Micromegas  
T. Zerguerras et al.  
to be published in NIMA*

# Gain fluctuations in gas detectors

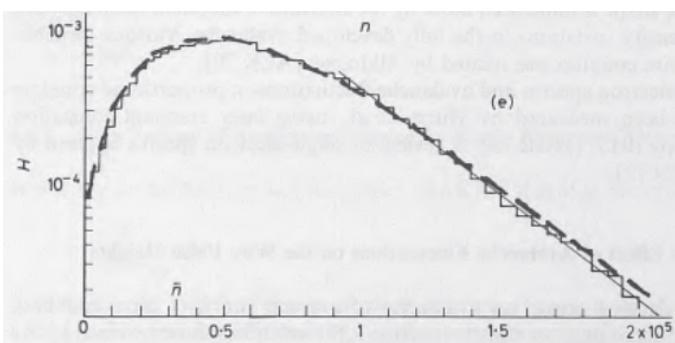
(e) SER Ne 95% iC<sub>4</sub>H<sub>10</sub> 5% - V<sub>Mesh</sub>=510V



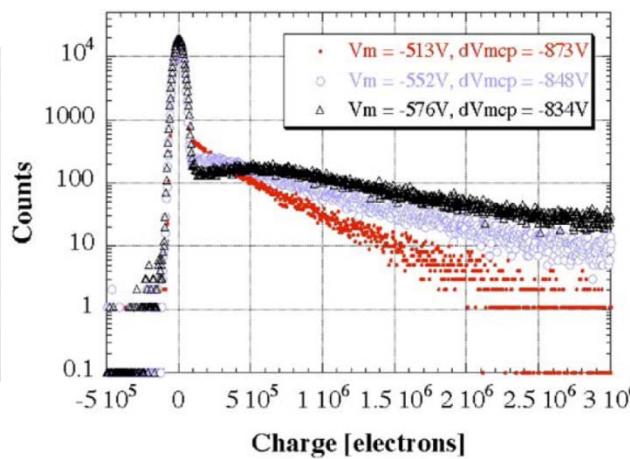
1 mm gap PPC  
NIMA 433 (1999) 513



Micromegas

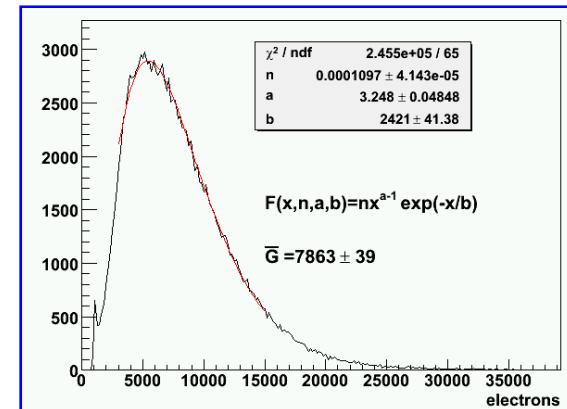


PPC, Z. Phys. 151 (1958) 563

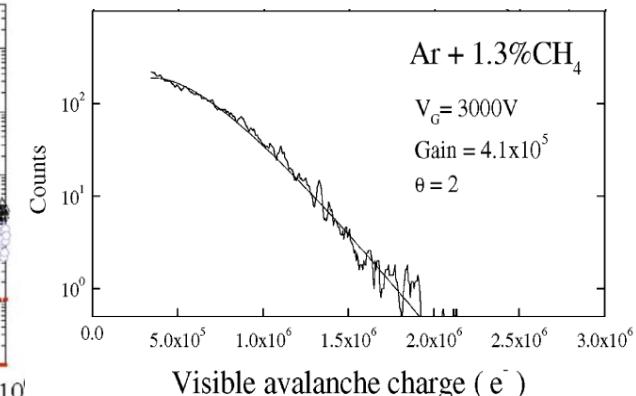


MCP+Micromegas, NIMA 535 (2004) 334

GEM, Bellazzini, IEEE 06, SanDiego



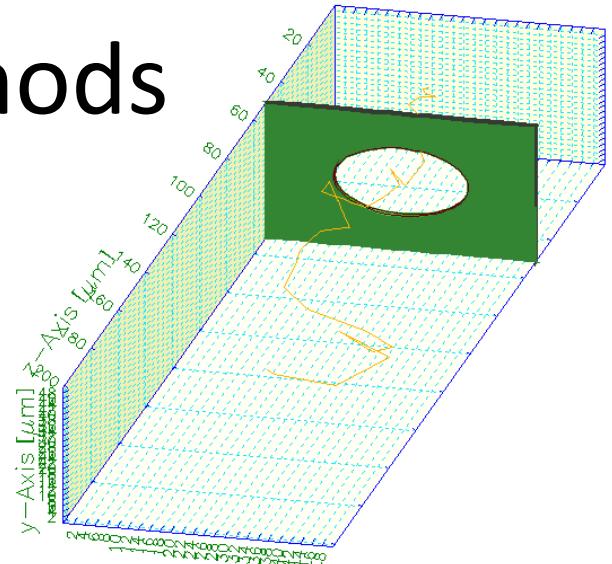
3 GEMs, NIMA 443 (2000) 164



# Investigation methods

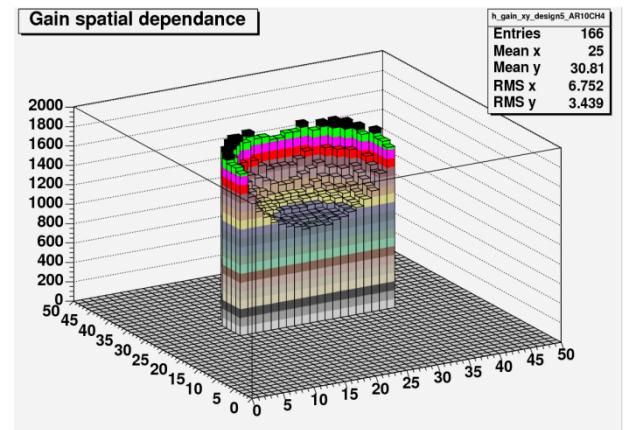
- **Simulation, since recently within GARFIELD:**

- Simulation of e- avalanche according to MAGBOLTZ cross-section database:  
*study of gas & field*
  - Simulation of e- tracking at microscopic scale in field maps (3D):  
*study of geometry*



- **On the experimental side:**

- Direct measurement of the distribution:
    - High gains, low noise electronics, single electron source
  - Indirect measurements
    - Do not provide the shape but some moments (variance)
    - Assuming Polya-like fluctuations, one obtains the shape



- In this talk, only indirect methods are presented  
The Polya parameter  $m$  is deduced from:
  - Trend of energy resolution and collection efficiency
  - Trend of single electron detection efficiency and gas gain

# Measurement of gain variance

- Energy resolution  $R$  and electron collection efficiency  $\eta$ 
  - $R$  decreases with the efficiency according to
  - $R^2 = F/N + b/\eta N + (1-\eta)/\eta N$
  - $R^2 = p_0 + p_1/\eta$   
 $p_0 = (F-1)/N$   
 $p_1 = (b+1)/N$
  - Measure  $R(\eta)$  at e.g. 5.9 keV, fix  $F$  and  $N$ , adjust  $b$  (i.e.  $m$ ) on data
- Single electron detection efficiency  $\kappa$  and gas gain  $G$ 
  - $\kappa$  increases with  $G$  as more avalanches end up above the detection threshold  $t$

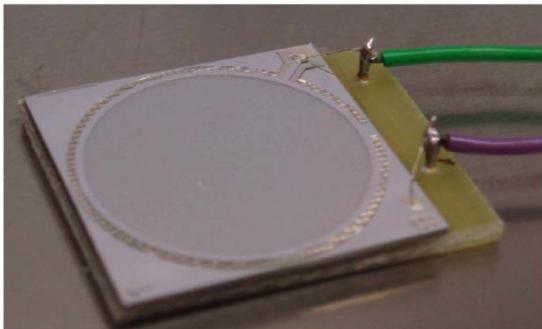
$$\kappa_m = \int_t^\infty p_m(g) dg$$

- Integral can be calculated for integer value of  $m$
- Count the number of e- from  $^{55}\text{Fe}$  conversions ( $N$ ) with TimePix
  - Measure  $N(G)$ , adjust  $\kappa(G, m)$  on this trend, keep  $m$  for which the fit is best

# Experimental set-up(s)

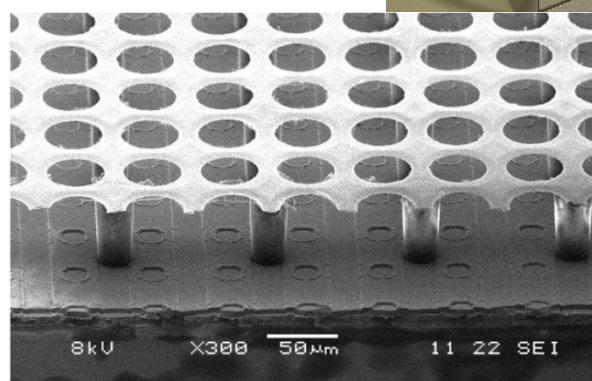
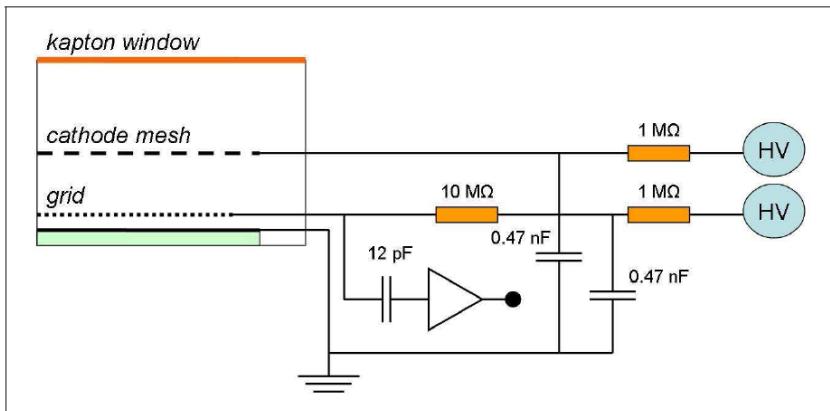
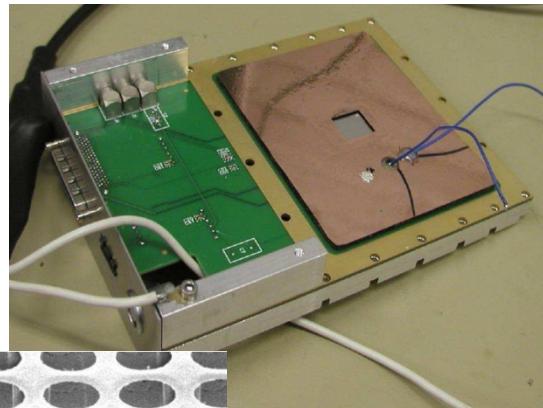
- **Measure 1:  $R(\eta)$**

- InGrid on bare wafer
- Preamp/shaper/ADC
- $^{55}\text{Fe}$  5.9 keV X-ray source
- Ar-based gas mixtures with  $i\text{C}_4\text{H}_{10}$  and  $\text{CO}_2$



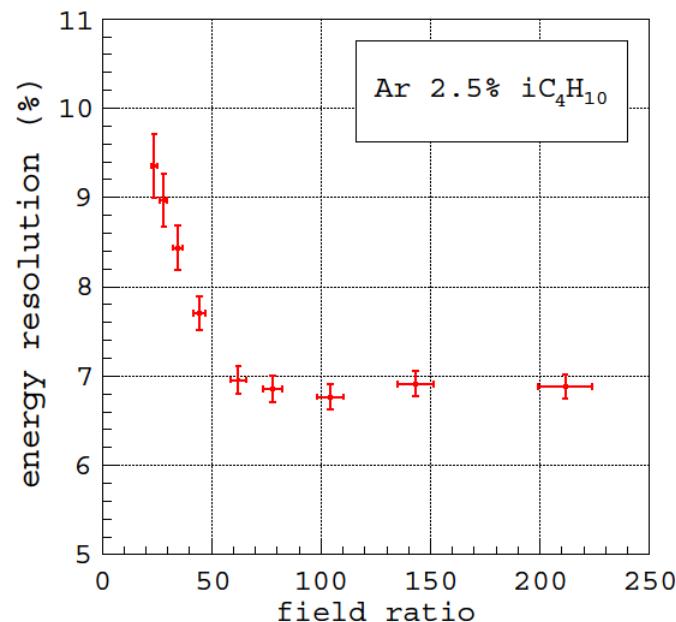
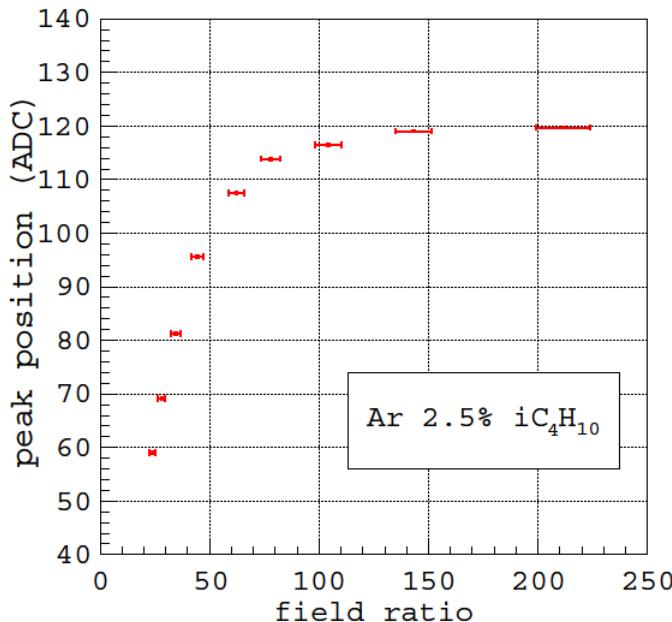
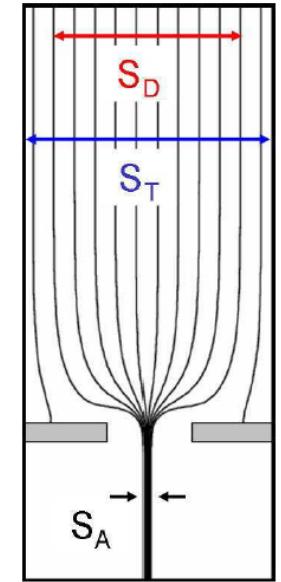
- **Measure 2:  $\kappa(G)$**

- InGrid on TimePix chip
- Pixelman and ROOT
- $^{55}\text{Fe}$  5.9 keV X-ray source
- Enough diffusion for counting
  - 10 cm drift gap
  - Ar 5%  $i\text{C}_4\text{H}_{10}$



# Energy resolution & collection

- Vary the collection efficiency with the field ratio
- Record  $^{55}\text{Fe}$  spectra at various field ratios
  - Look at peak position VS field ratio  
define arbitrarily peak maximum as  $\eta = 1$
  - Look at resolution VS collection
  - Adjust  $b$  on data points



# Energy resolution & collection

- Record  $^{55}\text{Fe}$  spectra at various field ratios
  - Look at peak position VS field ratio  
define arbitrarily peak maximum as  $\eta = 1$
  - Look at resolution VS collection
  - Fix  $F$  and  $N$ , adjust  $b$  on data points

Fit function:  
 $R = \sqrt{(p_0 + p_1/\eta)}$

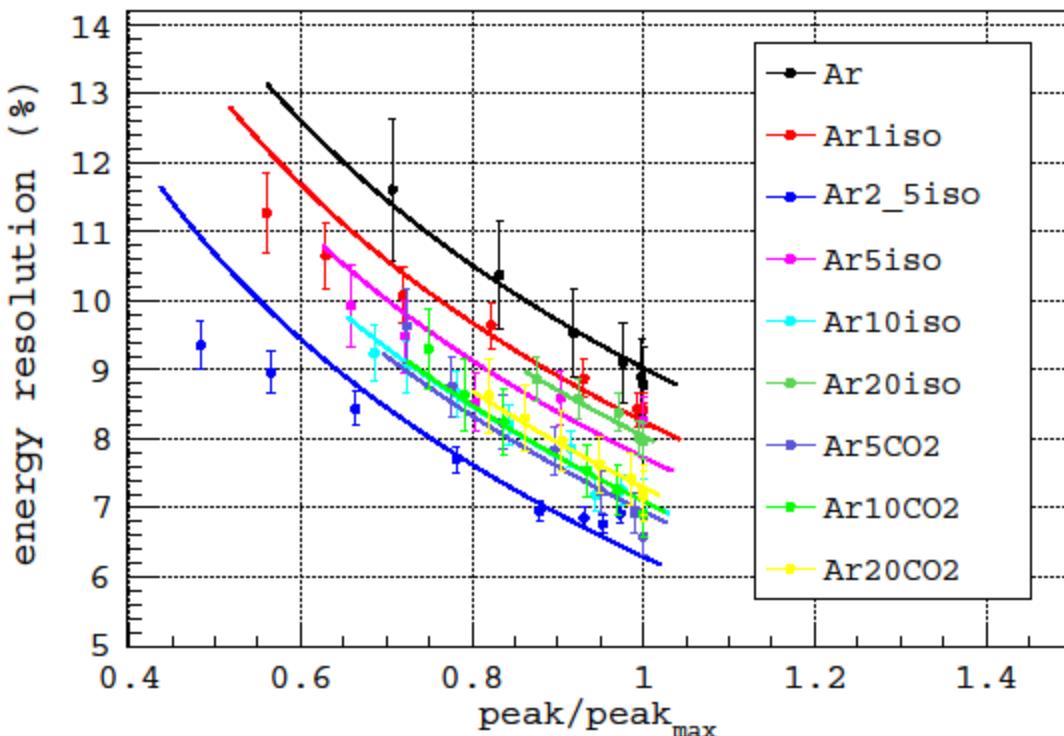
$$p_0 = (F-1)/N$$

$$p_1 = (b+1)/N$$

$F = 0.2$  in all mix.

$N = 230$  in Ar/iso

$N = 220$  in Ar/CO<sub>2</sub>



Gas	b	b_err	vb (%)	m=1/b
Ar	1,68	0,02	130	0,60
Ar1iso	1,37	0,01	117	0,73
Ar2_5iso	0,71	0,01	84	1,41
Ar5iso	1,18	0,02	109	0,85
Ar10iso	0,93	0,01	96	1,08
Ar20iso	1,29	0,01	114	0,78
Ar5CO <sub>2</sub>	0,86	0,02	93	1,16
Ar10CO <sub>2</sub>	0,91	0,02	95	1,10
Ar20CO <sub>2</sub>	0,97	0,02	98	1,03

- Rather low Polya parameter 0.6-1.4  
May be due to a poor grid quality
- Curves do not fit very well points  
Could let  $F$  or/and  $N$  free

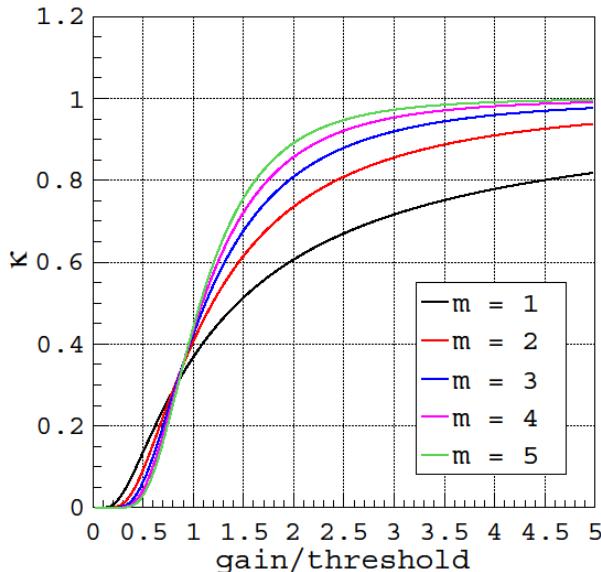
# Single electron detection efficiency and gain

- Trend depends on:
  - the threshold  $t$ , the gas gain  $G$  and  $m$

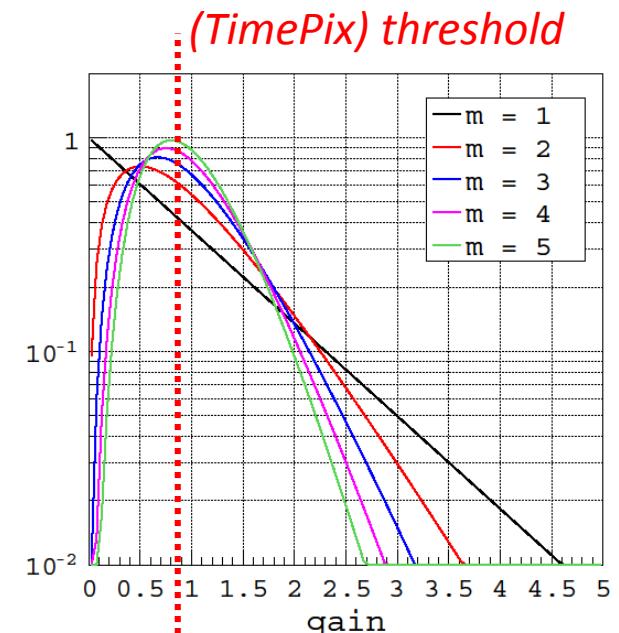
$$p_1(g) = \exp(-g/G)$$

$$p_2(g) = 4 \frac{1}{G} \frac{g}{G} \exp(-2g/G)$$

$$p_5(g) = \frac{3125}{24} \frac{1}{G} \left( \frac{g}{G} \right)^4 \exp(-5g/G)$$



$$\kappa_m = \int_t^\infty p_m(g) dg$$



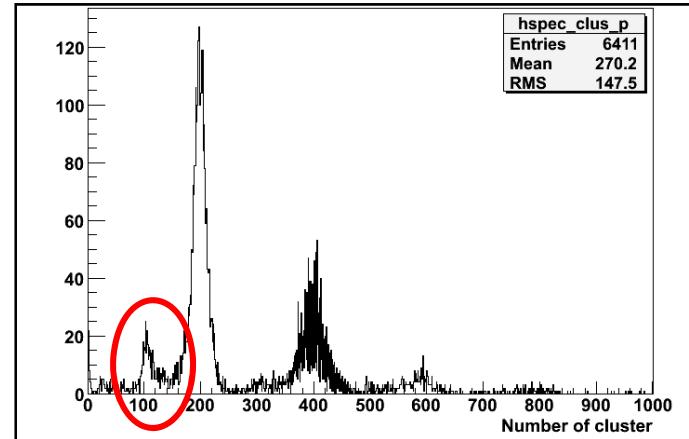
$$\kappa_1(t/G) = \exp(-t/G)$$

$$\kappa_2(t/G) = \exp(-2t/G) \left( 1 + 2 \frac{t}{G} \right)$$

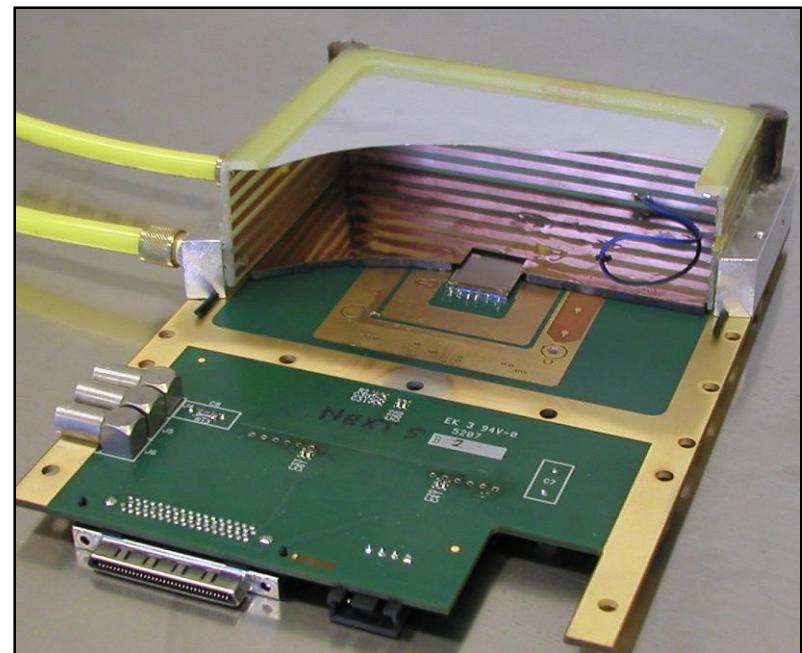
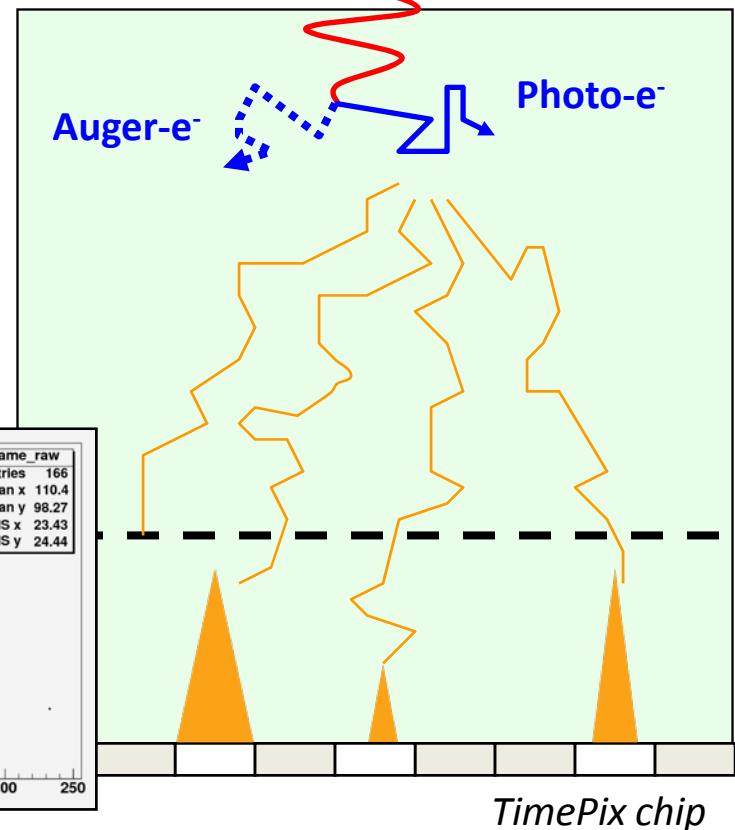
$$\kappa_5(t/G) = \exp(-5t/G) \left( \frac{625}{24} \left( \frac{t}{G} \right)^4 + \frac{125}{6} \left( \frac{t}{G} \right)^3 + \frac{25}{2} \left( \frac{t}{G} \right)^2 + 5 \left( \frac{t}{G} \right) + 1 \right)$$

# Single electron detection efficiency and gain

- Considering  $^{55}\text{Fe}$  conversions:  
the efficiency is proportionnal to the number of detected electrons at the chip
- Count the number of electrons at various gains
  - In the escape peak!
  - Apply cuts on the X and Y r.m.s. of the hits



$^{55}\text{Fe}$  X-ray  $E_0$ : 5.9 and 6.5 keV



# Single electron detection efficiency and gain

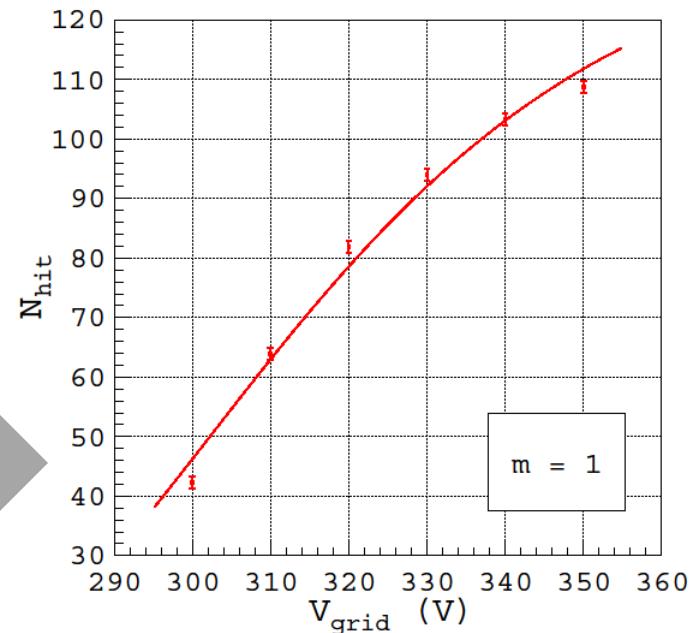
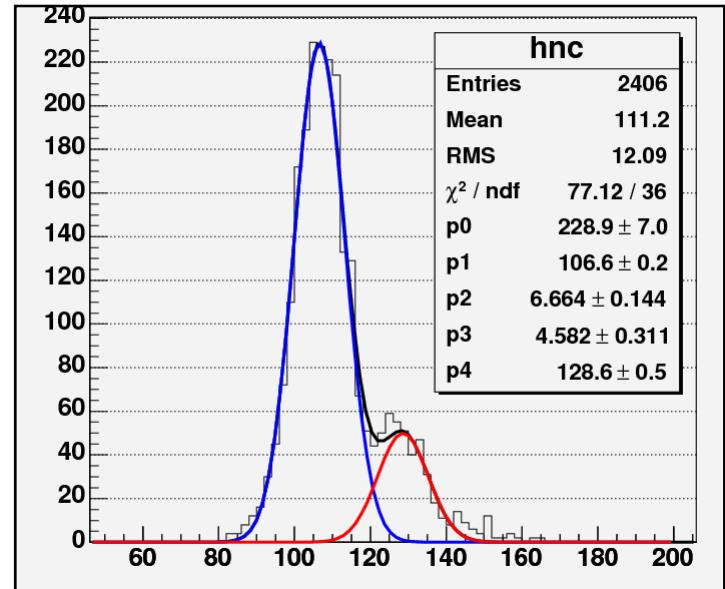
- Number of detected electrons at given voltage determined by
  - Adjusting 2 gaussians on escape peak
  - $K_{\text{beta}}$  parameters constrained by  $K_{\text{alpha}}$  ones
  - 3 free parameters
- Number of detected electrons and voltage
  - Use common gain parametrization
  - Fix  $p_2$  (slope of the gain curve)
  - 2 free parameters:  $t/A$  and  $\eta N$

$$N_d = \eta \kappa(m, t, G) N_p = \eta \kappa(m, t, V_g) N_p$$

$$G = A \exp(BV_g)$$

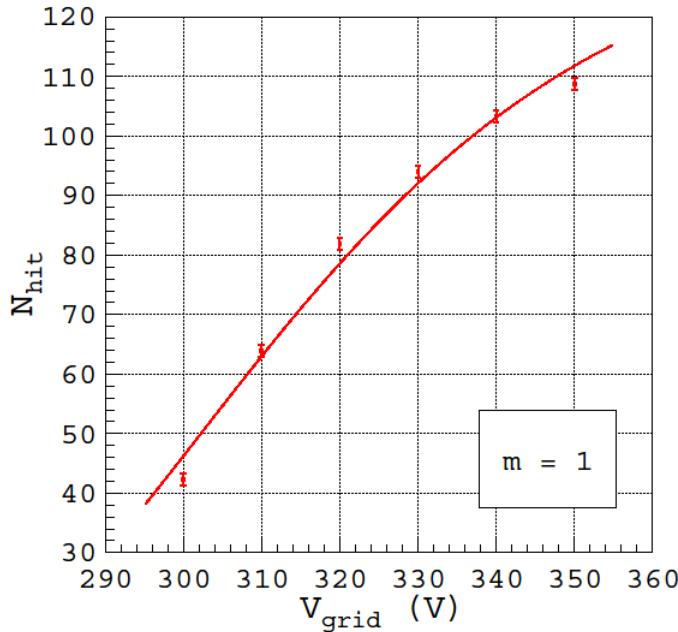
$$N_d = p_0 \cdot \exp\left(-p_1 \exp(-p_2 V_g)\right)$$

$$p_0 = \eta N_p \quad p_1 = t/A \quad p_2 = B$$

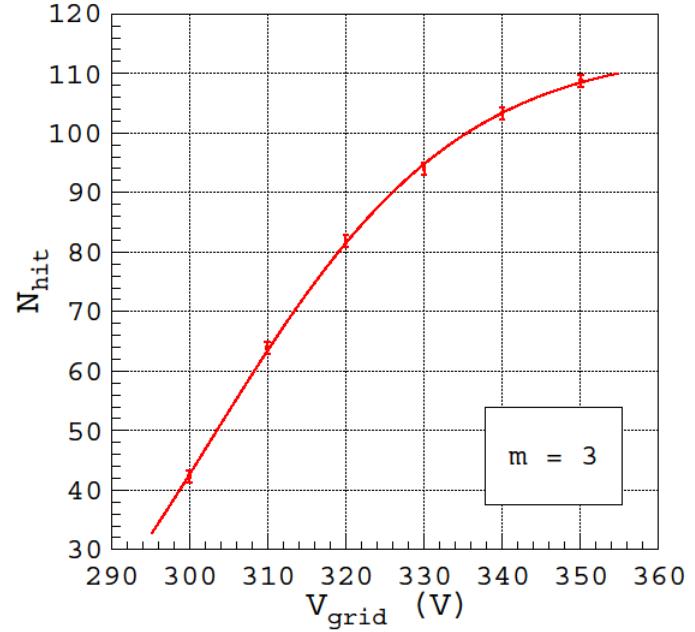


# Single electron detection efficiency and gain

$$\kappa_1(t/G) = \exp(-t/G)$$



$$\kappa_3(t/G) = \exp(-3t/G) \left( \frac{27}{6} \left( \frac{t}{G} \right)^2 + 3 \frac{t}{G} + 1 \right)$$



$m$	$rms$ (%)	$\chi^2$
1	100	39.43
2	71	3.08
<b>3</b>	<b>58</b>	<b>1.16</b>
4	50	1.41
5	45	1.60



Best fit for  $m = 3$   
Yields  $\sqrt{b} = 1/\sqrt{m} \sim 58\%$

- Also,  $\eta N = 115$  e-
- Upper limit on  $W(\text{Ar5iso}) < 25$  eV
- Correcting for un-efficiency:  
Upper limit on  $F(\text{Ar5iso}) < 0.3$

# Conclusion

- Two methods to investigate gas gain variance
  - Assuming Polya fluctuation, shape available for detector simulation
  - Energy resolution and collection efficiency simple (mesh readout)  
but a certain number of primary e- and Fano factor have to be assumed
  - Single e- detection efficiency and gain powerful (provide not only  $m$  but  $W$  and  $F$ )  
but a InGrid-equipped pixel chip is needed

4 main lines in an  $^{55}\text{Fe}$  spectrum

- Another one not presented
  - Energy resolution and number of primary electrons

$$R^2 = p_0/N$$
$$p_0 = F+b$$

